Early warning sensor sniffs out cities' harmful gas
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An integrated detector device could form the basis of a distributed air-quality sensor network.

The design for an electronic sensor that sounds the alarm if toxic industrial and vehicle-exhaust gases exceed safe levels could lead to cleaner air in many cities. KAUST researchers have developed a small, low-cost device that senses nitrogen dioxide (NO\textsubscript{2}); it could be deployed in potential hotspots around cities, alerting authorities if levels of the harmful gas start to spike.

Most existing NO\textsubscript{2} detectors are large, complex machines suited to laboratory use, whereas the compact new device is designed to form part of a distributed network of air quality sensors. "Our sensor exhibits very high sensitivity and selectivity for NO\textsubscript{2}, operates at room temperature and has very low power consumption," says Mani Vijjapu, a Ph.D. student in Khaled Salama's lab, who led the research.

However, the biggest advantage over previous designs is that the gas detector brings together all the necessary sensing and signal processing components within a simple, fully integrated system, Vijjapu says. Despite its simplicity, the device's output signal varies according to NO\textsubscript{2} concentration.

The gas detector's high performance, low power consumption and fully integrated design all stem from the NO\textsubscript{2}-sensing thin-film transistor at the core of the device. Previous sensors have used metal oxides that are sensitive to NO\textsubscript{2} only when heated or continuously irradiated with light. This time, the team used a semiconductor called indium gallium zinc oxide (IGZO). "As a gas sensor, the IGZO-based thin-film transistor has multifaceted benefits," says Sandeep Surya, a postdoctoral researcher in Salama's team.

The IGZO thin-film transistor acts as both an electronic component of the device and also as the NO\textsubscript{2}-sensing layer. The strongly electron-accepting NO\textsubscript{2} molecule is drawn to the electrons on the transistor's surface. The more NO\textsubscript{2} molecules that adhere to the IGZO, the more electrons are depleted from its surface, altering its electronic output and triggering an NO\textsubscript{2} detection alert.

After a detection event, the sensor is reset by reviving the IGZO layer with the light from an integrated blue LED. Similar to a solar cell, the light generates negatively charged electrons and positively charged holes in the IGZO, which neutralizes the adsorbed NO\textsubscript{2} and releases it from the surface. "This is the first study to achieve sensing and revival of a semiconducting metal oxide-based thin-film transistor sensor at room temperature," says Surya.

"The next step is to translate our research into a prototype and maybe even a product by working with industry," Salama says. "We are also interested in exploring other materials to detect other hazardous gases in the environment."

More information: Mani Teja Vijjapu et al. Fully

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